

## **KSC4468**

## **Audio Power Amplifier**

- High Current Capability : I<sub>C</sub>=15A
- High Power Dissipation
- Wide S.O.A
- Complement to KSA1695



# **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings $\rm T_{C} = 25^{\circ}C$ unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       | 160        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    | 140        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | 6          | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | 8          | Α     |
| I <sub>CP</sub>  | Collector Current (Pulse)                    | 16         | Α     |
| PC               | Collector Dissipation (T <sub>C</sub> =25°C) | 80         | W     |
| TJ               | Junction Temperature DataSheet4U.com         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 55 ~ 150 | °C    |

## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                               | Parameter                            | Test Condition   | Min.     | Тур. | Max. | Units |
|--------------------------------------|--------------------------------------|--|----------|------|------|-------|
| BV <sub>CBO</sub>                    | Collector-Base Breakdown Voltage     | $I_C=5mA$ , $I_E=0$  | 160      |      |      | V     |
| BV <sub>CEO</sub>                    | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> =10mA, R <sub>BE</sub> =∞   | 140      |      |      | V     |
| BV <sub>EBO</sub>                    | Emitter-Base Breakdown Voltage       | $I_E=5mA$ , $I_C=0$  | 6        |      |      | V     |
| I <sub>CBO</sub>                     | Collector Cut-off Current            | $V_{CB}$ =80V, $I_{E}$ =0  |          |      | 0.1  | mA    |
| I <sub>EBO</sub>                     | Emitter Cut-off Current              | $V_{EB}=4V$ , $I_{C}=0$  |          |      | 0.1  | mA    |
| h <sub>FE1</sub><br>h <sub>FE2</sub> | * DC Current Gain                    | V <sub>CE</sub> =5V, I <sub>C</sub> =1A<br>V <sub>CE</sub> =5V, I <sub>C</sub> =6A | 60<br>20 |      | 200  |       |
| V <sub>CE</sub> (sat)                | Collector-Emitter Saturation Voltage | I <sub>C</sub> =5A, I <sub>B</sub> =0.5A   |          |      | 2.5  | V     |
| V <sub>BE</sub> (on)                 | Base-Emitter ON Voltage              | $V_{CE}$ =5V, $I_{C}$ =1A  |          |      | 1.5  | V     |
| f <sub>T</sub>                       | Current Gain Bandwidth Product       | $V_{CE}$ =5V, $I_{C}$ =1A  |          | 30   |      | MHz   |
| C <sub>ob</sub>                      | Output Capacitance                   | V <sub>CB</sub> =10V, f=1MHz   |          | 210  |      | pF    |
| t <sub>ON</sub>                      | Turn ON Time                         | V <sub>CC</sub> =20V,  |          | 0.26 |      | μs    |
| t <sub>F</sub>                       | Fall Time                            | I <sub>C</sub> =1A=10I <sub>B1</sub> =-10I <sub>B2</sub>                           |          | 0.68 |      | μs    |
| t <sub>STG</sub>                     | Storage Time                         | $R_L=20\Omega$   |          | 6.68 |      | μs    |

## **h**<sub>FE</sub> Classification

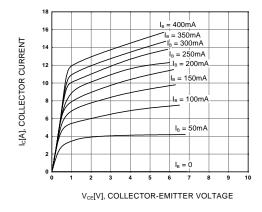
| Classification   | 0        | Y         |  |
|------------------|----------|-----------|--|
| h <sub>FE1</sub> | 60 ~ 120 | 100 ~ 200 |  |

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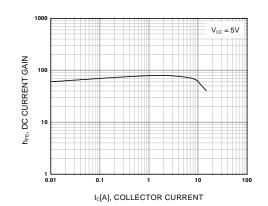
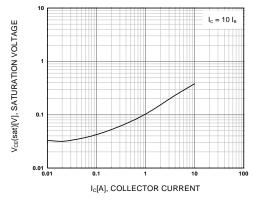


Figure 1. Static Characterstic

Figure 2. DC current Gain



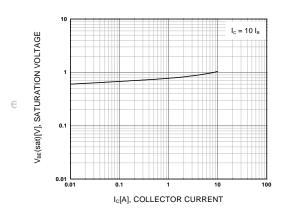
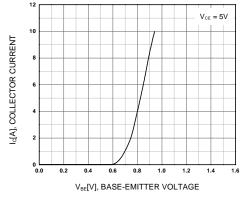


Figure 3. Collector-Emitter Saturation Voltage

Figure 4. Base-Emitter Saturation Voltage



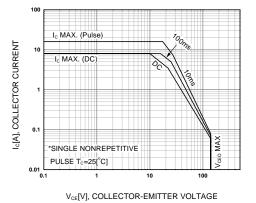


Figure 5. Base-Emitter On Voltage

Figure 6. Safe Operating Area

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# **Typical Characteristics** (Continued)

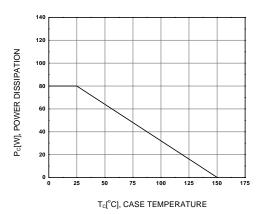


Figure 7. Power Derating

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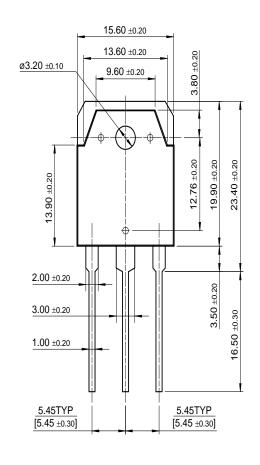
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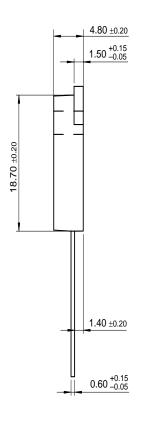
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Dimensions in Millimeters

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